

Features and Benefits

- □ Wide operating voltage range from 3.5V to 24V
- Medium sensitivity
- CMOS technology
- □ Chopper-stabilized amplifier stage
- Low current consumption
- Open drain output
- □ Thin SOT23 3L and flat TO-92 3L both RoHS Compliant packages

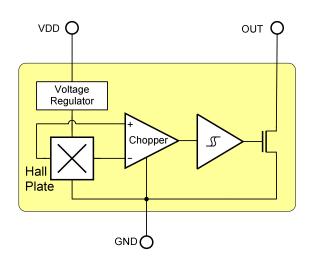
Application Examples

- □ Automotive, Consumer and Industrial
- Solid-state switch
- □ Interrupter
- Current detector
- Proximity detection

Ordering Information

Part No.	Temperature Code	Package Code
US5781	E (-40 ℃ to 85 ℃)	SE (TSOT-3L)
US5781	E (-40 ℃ to 85 ℃)	UA (TO-92)
US5781	L (-40 ℃ to 150 ℃)	SE (TSOT-3L)
US5781	L (-40 ℃ to 150 ℃)	UA (TO-92)

1 Functional Diagram



2 General Description

The Melexis US5781 is a unipolar Hall-effect switch designed in mixed signal CMOS technology.

The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, Schmitt trigger and an open-drain output driver, all in a single package.

Thanks to its wide operating voltage range and extended choice of temperature range, it is suitable for use in automotive and solid state switch applications.

The device is delivered in a Thin Small Outline Transistor (TSOT) for surface mount process and in a Plastic Single In Line (TO-92 flat) for throughhole mount.

Both 3-lead packages are RoHS compliant.



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3 Glossary of Terms

MilliTesla (mT), Gauss	Units of magnetic flux density:
	1mT = 10 Gauss
RoHS	Restriction of Hazardous Substances
TSOT	Thin Small Outline Transistor (TSOT package) – also referred with the Melexis package code "SE"
ESD	Electro-Static Discharge
BLDC	Brush-Less Direct-Current

4 Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage	V _{DD}	28	V
Supply Current	IDD	50	mA
Output Voltage	Vout	28	V
Output Current	Іоит	50	mA
Storage Temperature Range	Ts	-50 to 150	°C
Maximum Junction Temperature	TJ	165	°C

Table 1: Absolute maximum ratings

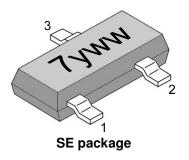
Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

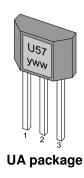
Operating Temperature Range	Symbol	Value	Units
Temperature Suffix "E"	TA	-40 to 85	°C
Temperature Suffix "L"	TA	-40 to 150	°C

5 Pin Definitions and Descriptions

SE Pin №	UA Pin №	Name	Туре	Function
1	1	VDD	Supply	Supply Voltage pin
2	3	OUT	Output	Open Drain Output pin
3	2	GND	Ground	Ground pin

Table 2: Pin definitions and descriptions







6 General Electrical Specifications

DC Operating Parameters $T_A = 25^{\circ}C$, $V_{DD} = 12V$ (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	Vdd	Operating	3.5		24	V
Supply Current	I _{DD}	B < B _{RP}	0.5	2.5	5	mA
Output Saturation Voltage	V _{DSon}	IOUT = 20mA, B > BOP		0.3	0.5	V
Output Leakage Current	IOFF	$B < B_{RP}, V_{OUT} = 24V$		0.01	10	μΑ
Output Rise Time	tr	R∟ = 1kΩ, C∟ = 20pF		0.25		μs
Output Fall Time	tr	R∟ = 1kΩ, C∟ = 20pF		0.25		μs
Maximum Switching Frequency	F _{SW}			10		KHz
SE Package Thermal Resistance	R _{TH}	Single layer (1S) Jedec board		301		°C/W
UA Package Thermal Resistance	Rth			200		°C/W

Table 3: Electrical specifications

7 Magnetic Specifications

DC Operating Parameters $T_A = 25^{\circ}C$, $V_{DD} = 12V$ (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Operating Point	BOP		7	12	15	тт
Release Point	Brp		3.5	7.5	10	тт
Hysteresis	Внузт		2	5	7	mT

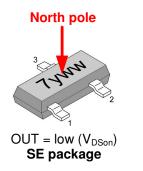
Table 4: Magnetic specifications

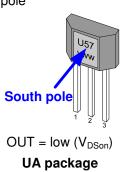
8 Output Behaviour versus Magnetic Pole

DC Operating Parameters $T_A = -40^{\circ}$ C to 150° C, $V_{DD} = 3.5$ V to 24V (unless otherwise specified)

Parameter	Test Conditions (SE)	OUT (SE)	OUT (UA)
South pole	B > B _{OP}	High	Low
Null or weak magnetic field	$B \rightarrow 0$ or $B < B_{RP}$	High	High
North pole	B > B _{OP}	Low	High

Table 5: Output behaviour versus magnetic pole







9 Detailed General Description

Based on mixed signal CMOS technology, Melexis US5781 is a Hall-effect device with medium magnetic sensitivity. Its sensitivity enables high accuracy in position sensing by the use of small air gap.

The chopper-stabilized amplifier uses switched capacitor technique to suppress the offset generally observed with Hall sensors and amplifiers. The CMOS technology makes this advanced technique possible and contributes to smaller chip size and lower current consumption than bipolar technology. The small chip size is also an important factor to minimize the effect of physical stress.

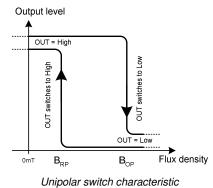
This combination results in more stable magnetic characteristics and enables faster and more precise design.

The wide operating voltage from 3.5V to 24V, "L" and "E" operating temperature range and low current consumption make this device especially suitable for automotive and solid state switch applications.

The output signal is open-drain type. Such output allows simple connectivity with TTL or CMOS logic by using a pull-up resistor tied between a pull-up voltage and the device output.

10 Unique Features

The US5781 exhibits unipolar magnetic switching characteristics. Therefore, it operates only with one magnetic pole.



The UA package is south pole active: Applying a south magnetic pole greater than B_{OP} facing the branded side of the package switches the output low.

The SE package is north pole active: Applying a north magnetic pole greater than B_{OP} facing the branded side of the package switches the output low.

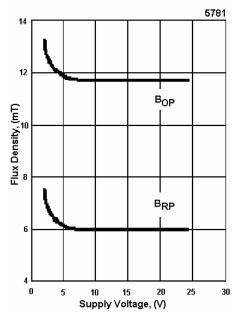
Removing the magnetic field $(B\rightarrow 0)$ switches the output high. The use of the opposite magnetic pole facing the branded side does not affect the output state.

A magnetic hysteresis B_{HYST} keeps B_{OP} and B_{RP} separated by a minimal value. This hysteresis prevents output oscillation near the switching point.

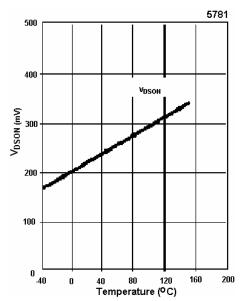


11 Performance Graphs

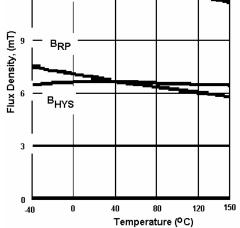
11.1 Typical Magnetic Switch Points vs V_{DD}







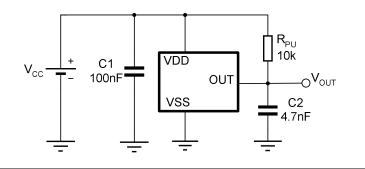
11.2 Magnetic Switch Points vs Temperature



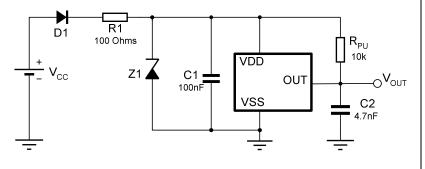


12 Application Information

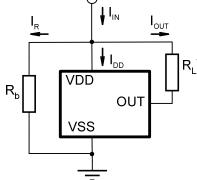
12.1 Typical Three-Wire Application Circuit



12.3 Automotive and Harsh, Noisy Environments Three-Wire Circuit



12.2 Two-Wire Circuit V_{DD} I_{OUT} ↓ I_{DD} VDD R_r



Note:

With this circuit, precise ON and OFF currents can be detected using only two connecting wires.

The resistors RL and Rb can be used to bias the input current. Refer to the part specifications for limiting values.

 $B_{RP}: I_{OFF} = I_R + I_{DD} = V_{DD}/R_b + I_{DD}$ B_{OP} : $I_{ON} = I_{OFF} + I_{OUT} = I_{OFF} + V_{DD}/R_L$

13 Application Comments

For proper operation, a 100nF bypass capacitor should be placed as close as possible to the device between the V_{DD} and ground pin.

For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the V_{DD} pin. When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum (V_{CC} / R1 \leq 50mA)
- the resulting device supply voltage V_{DD} has to be higher than V_{DD} min ($V_{DD} = V_{CC} R1.I_{DD}$)
- the resistor has to withstand the power dissipated in reverse voltage condition ($P_D = V_{CC}^2 / R1$)

When using a diode, a reverse current cannot flow and the voltage drop is almost constant (~0.7V).

Therefore, a $100\Omega/0.25W$ resistor for 5V application and a diode for higher supply voltage are recommended. Both solutions provide the required reverse voltage protection.

When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended that figure 13.3 from the Application Information section is used. The low-pass filter formed by R1 and C1 and the zener diode Z1 bypass the disturbances or voltage spikes occurring on the device supply voltage V_{DD}. The diode D1 provides additional reverse voltage protection.



14 Standard information regarding manufacturability of Melexis products with different soldering processes

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

- IPC/JEDEC J-STD-020
 Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices
 (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113 Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing (reflow profiles according to table 2)

Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20 Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15 Resistance to soldering temperature for through-hole mounted devices

Iron Soldering THD's (<u>Through Hole Devices</u>)

• EN60749-15 Resistance to soldering temperature for through-hole mounted devices

Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

• EIA/JEDEC JESD22-B102 and EN60749-21 Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: http://www.melexis.com/quality.asp

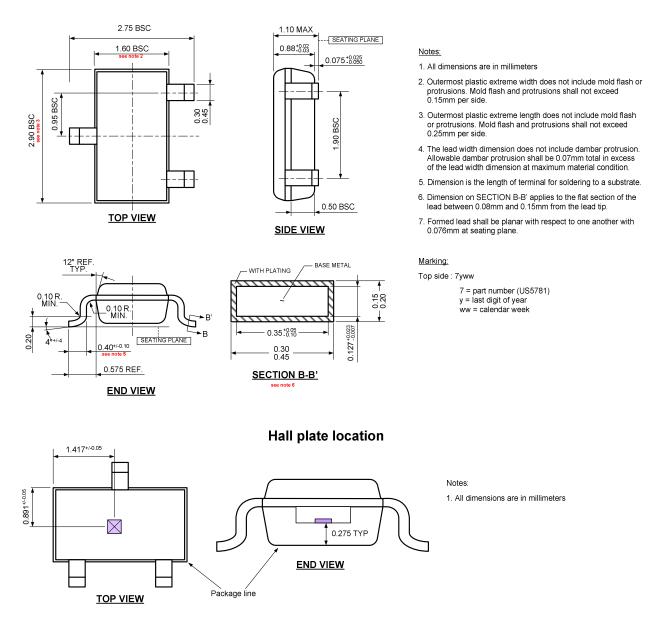
15 ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). Always observe Electro Static Discharge control procedures whenever handling semiconductor products.



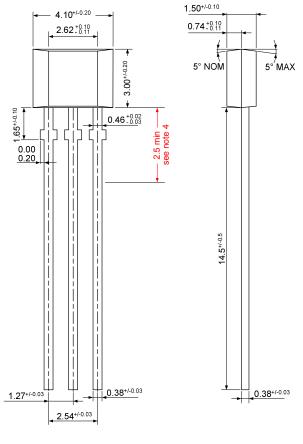
16 Package Information

16.1 SE Package (TSOT-3L)





16.2 UA Package (TO-92 flat)



Notes:

- 1. All dimensions are in millimeters
- 2. Package dimension exclusive molding flash.
- 3. The end flash shall not exceed 0.127 mm on each side.
- 4. To preserve reliability, it is recommended to have total lead length equal to 2.5mm minimum, measured from the package line.

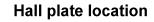
<u>Marking:</u>

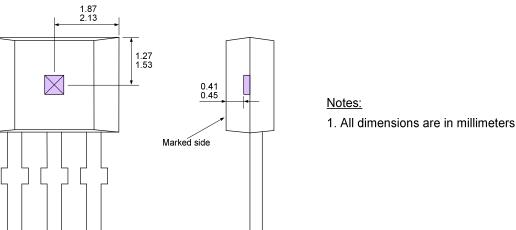
1st Line : U57 - Part number (US5781)

2nd Line : yww

y - last digit of year ww - calendar week









17 Disclaimer

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